

Octal bus transceiver/register (3-State)

74LVC646A

FEATURES

- Wide supply voltage range of 1.2V to 3.6V
- Flow-through pin-out architecture
- In accordance with JEDEC standard no. 8-1A
- CMOS low power consumption
- Direct interface with TTL levels
- 5 Volt tolerant inputs/outputs, for interfacing with 5 Volt logic

DESCRIPTION

The 74LVC646A is a high performance, low-power, low-voltage Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3V or 5.0V devices. In 3-State operation, outputs can handle 5V. This feature allows the use of these devices as translators in a mixed 3.3V/5V environment.

The 74LVC646A consist of non-inverting bus transceiver circuits with 3-State outputs, D-type flip-flops and control circuitry arranged

for multiplexed transmission of data directly from the internal registers. Data on the 'A' or 'B' bus will be clocked in the internal registers, as the appropriate clock (CPAB or CPBA) goes to a HIGH logic level. Output enable ($\overline{OE}$) and direction (DIR) inputs are provided to control the transceiver function. In the transceiver mode, data present at the high-impedance port may be stored in either the 'A' or 'B' register, or in both. The select source inputs (SAB and SBA) can multiplex stored and real-time (transparent mode) data.

The direction (DIR) input determines which bus will receive data when $\overline{OE}$ is active (LOW). In the isolation mode ($\overline{OE}$ = HIGH), 'A' data may be stored in the 'B' register and/or 'B' data may be stored in the 'A' register.

When an output function is disabled, the input function is still enabled and may be used to store and transmit data. Only one of the two buses, 'A' or 'B' may be driven at a time.

The '646A' is functionally identical to the '648A' but has non-inverting data paths.

QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^{\circ}\text{C}$; $t_r = t_f \leq 2.5 \text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t_{PHL}/t_{PLH}	Propagation delay An to Yn	$C_L = 50\text{pF}$ $V_{CC} = 3.3\text{V}$	3.9	ns
f_{max}	Maximum clock frequency		250	MHz
C_I	Input capacitance		5.0	pF
$C_{I/O}$	Input/output capacitance		10	pF
C_{PD}	Power dissipation capacitance per gate	Notes 1, 2	26	pF

NOTES:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW)
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:
 f_i = input frequency in MHz; C_L = output load capacitance in pF;
 f_o = output frequency in MHz; V_{CC} = supply voltage in V;
 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.
2. The condition is $V_I = \text{GND to } V_{CC}$.

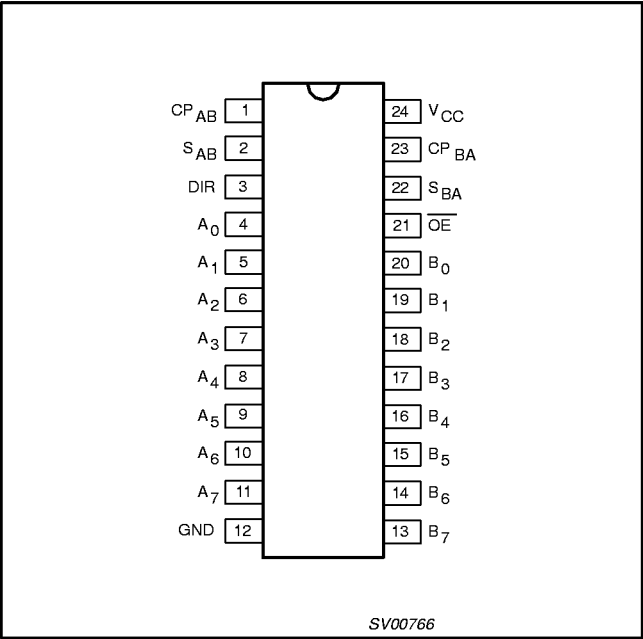
ORDERING AND PACKAGE INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
24-Pin Plastic SO	$-40^{\circ}\text{C to } +85^{\circ}\text{C}$	74LVC646A D	74LVC646A D	SOT137-1
24-Pin Plastic SSOP Type II	$-40^{\circ}\text{C to } +85^{\circ}\text{C}$	74LVC646A DB	74LVC646A DB	SOT340-1
24-Pin Plastic TSSOP Type I	$-40^{\circ}\text{C to } +85^{\circ}\text{C}$	74LVC646A PW	7LVC646APW DH	SOT355-1

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PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1	CP _{AB}	'A' to 'B' clock input (LOW-to-HIGH, edge-triggered)
2	S _{AB}	Select 'A' to 'B' source input
3	DIR	Direction control input
4, 5, 6, 7, 8, 9, 10, 11	A ₀ to A ₇	'A' data inputs/outputs
12	GND	Ground (0V)
20, 19, 18, 17, 16, 15, 14, 13	B ₀ to B ₇	'B' data inputs/outputs
21	$\overline{\text{OE}}$	Output enable input (active LOW)
22	S _{BA}	Select 'B' to 'A' source input
23	CP _{BA}	'B' to 'A' clock input (LOW-to-HIGH, edge-triggered)
24	V _{CC}	Positive supply voltage

FUNCTION TABLE

INPUTS						DATA I/O *		FUNCTION
$\overline{\text{OE}}$	DIR	CP _{AB}	CP _{BA}	S _{AB}	S _{BA}	A ₀ to A ₇	B ₀ to B ₇	
X	X	↑	X	X	X	input	un *	store A, B unspecified *
X	X	X	↑	X	X	un *	input	store B, A unspecified *
H	X	↑	↑	X	X	input	input	store A and B data, isolation hold storage
H	X	H or L	H or L	X	X			
L	L	X	X	X	L	output	input	real-time B data to A bus
L	L	X	H or L	X	H			stored B data to A bus
L	H	X	X	L	X	input	output	real-time A data to B bus
L	H	H or L	X	H	X			stored A data to B bus

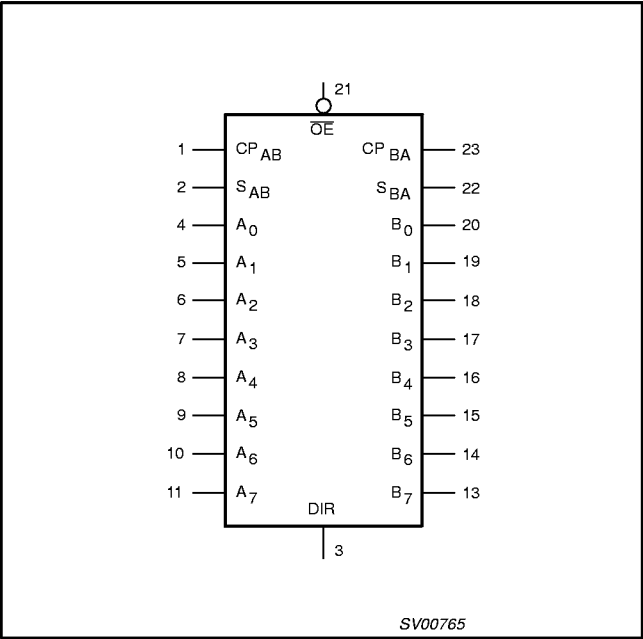
* The data output functions may be enabled or disabled by various signals at the $\overline{\text{OE}}$ and DIR inputs. Data input functions are always enabled, i.e., data at the bus inputs will be stored on every LOW-to-HIGH transition on the clock inputs.

un = unspecified
H = HIGH voltage level
L = LOW voltage level
X = Don't care
↑ = LOW-to-HIGH level transition

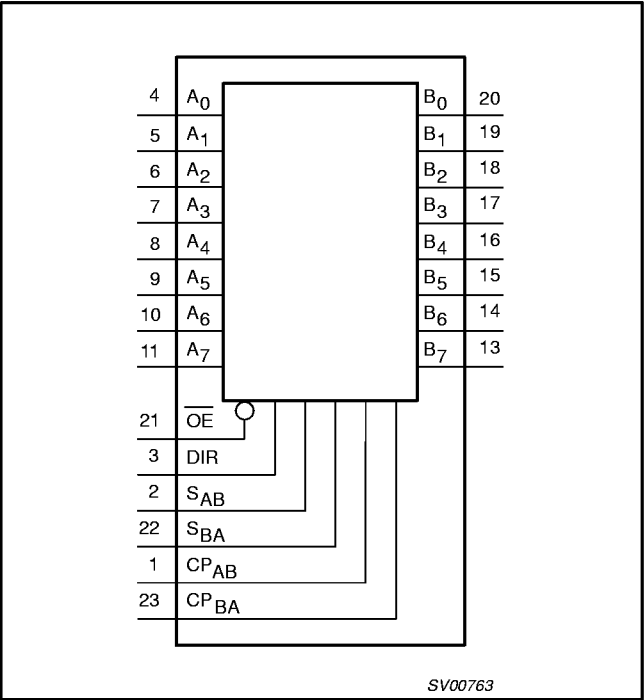
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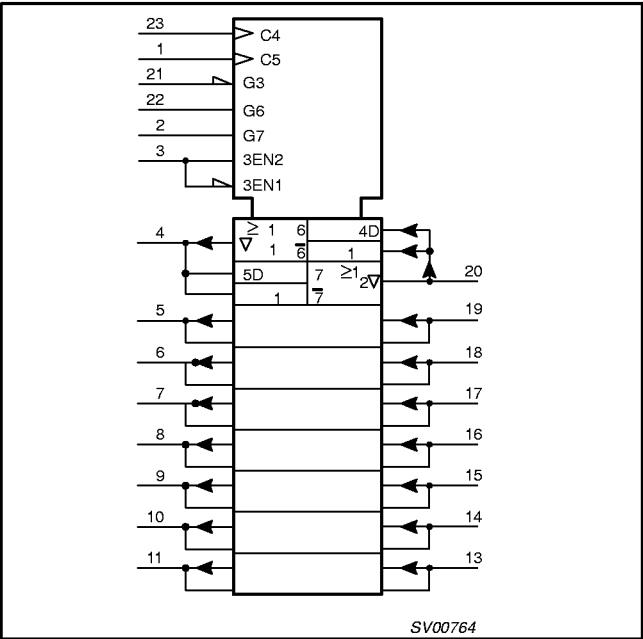
LOGIC SYMBOL



FUNCTIONAL DIAGRAM



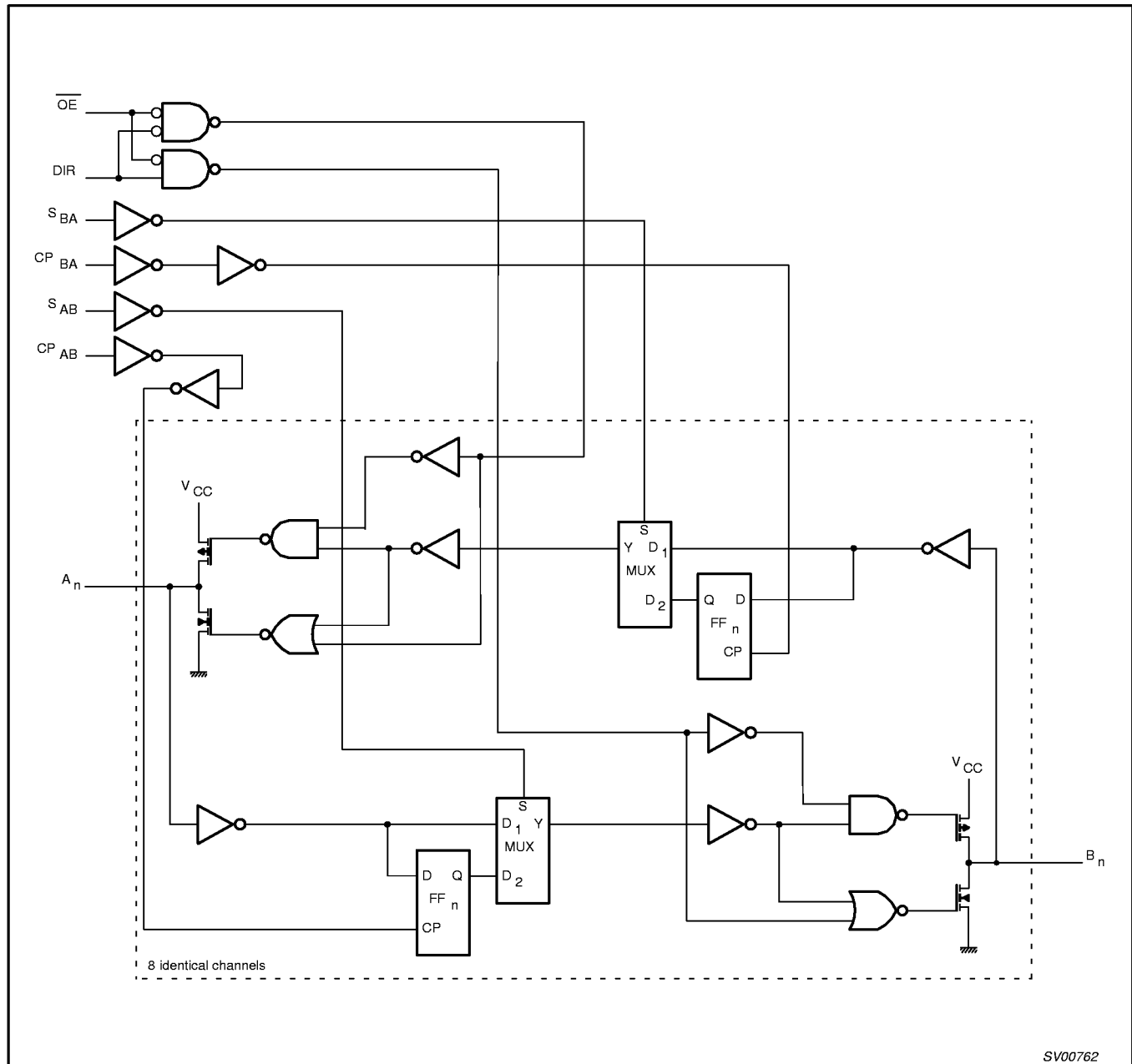
LOGIC SYMBOL (IEEE/IEC)



Octal bus transceiver/register (3-State)

74LVC646A

LOGIC DIAGRAM



SV00762

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIMITS		UNIT
			MIN	MAX	
V_{CC}	DC supply voltage (for max. speed performance)		2.7	3.6	V
	DC supply voltage (for low-voltage applications)		1.2	3.6	
V_I	DC input voltage range		0	5.5	V
V_O	DC output voltage range; output HIGH or LOW state		0	V_{CC}	V
	DC output voltage range; output 3-State		0	5.5	
T_{amb}	Operating free-air temperature range		-40	+85	°C
t_r, t_f	Input rise and fall times	$V_{CC} = 1.2$ to $2.7V$ $V_{CC} = 2.7$ to $3.6V$	0 0	20 10	ns/V

ABSOLUTE MAXIMUM RATINGS¹

In accordance with the Absolute Maximum Rating System (IEC 134)

Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		-0.5 to +6.5	V
I_{IK}	DC input diode current	$V_I < 0$	-50	mA
V_I	DC input voltage	Note 2	-0.5 to +6.5	V
I_{OK}	DC output diode current	$V_O > V_{CC}$ or $V_O < 0$	±50	mA
V_O	DC output voltage; output HIGH or LOW	Note 2	-0.5 to $V_{CC} + 0.5$	V
	DC output voltage; output 3-State	Note 2	-0.5 to 6.5	
I_O	DC output diode current	$V_O = 0$ to V_{CC}	±50	mA
I_{GND}, I_{CC}	DC V_{CC} or GND current		±100	mA
T_{stg}	Storage temperature range		-65 to +150	°C
P_{TOT}	Power dissipation per package – plastic mini-pack (SO)	above +70°C derate linearly with 8 mW/K	500	mW
	– plastic shrink mini-pack (SSOP and TSSOP)	above +60°C derate linearly with 5.5 mW/K	500	

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

Octal bus transceiver/register (3-State)

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	TEST CONDITIONS		LIMITS			UNIT
				Temp = -40°C to +85°C			
				MIN	TYP ¹	MAX	
V _{IH}	HIGH level Input voltage	V _{CC} = 1.2V	V _{CC}			V	
		V _{CC} = 2.7 to 3.6V	2.0				
V _{IL}	LOW level Input voltage	V _{CC} = 1.2V			GND	V	
		V _{CC} = 2.7 to 3.6V			0.8		
V _{OH}	HIGH level output voltage	V _{CC} = 2.7V; V _I = V _{IH} or V _{IL} ; I _O = -12mA	V _{CC} - 0.5			V	
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = -100μA	V _{CC} - 0.2	V _{CC}			
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = -18mA	V _{CC} - 0.6				
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = -24mA	V _{CC} - 0.8				
V _{OL}	LOW level output voltage	V _{CC} = 2.7V; V _I = V _{IH} or V _{IL} ; I _O = 12mA			0.40	V	
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = 100μA		GND	0.20		
		V _{CC} = 3.0V; V _I = V _{IH} or V _{IL} ; I _O = 24mA			0.55		
I _I	Input leakage current	V _{CC} = 3.6V; V _I = 5.5V or GND	Not for I/O pins		± 0.1	± 5	μA
I _{IHZ} /I _{ILZ}	Input current for common I/O pins	V _{CC} = 3.6V; V _I = V _{CC} or GND			± 0.1	± 15	μA
I _{OZ}	3-State output OFF-state current	V _{CC} = 3.6V; V _I = V _{IH} or V _{IL} ; V _O = 5.5V or GND			0.1	± 10	μA
I _{OFF}	Power off leakage current	V _{CC} = 0.0V; V _I or V _O = 5.5V			0.1	± 10	μA
I _{CC}	Quiescent supply current	V _{CC} = 3.6V; V _I = V _{CC} or GND; I _O = 0			0.1	10	μA
ΔI _{CC}	Additional quiescent supply current per input pin	V _{CC} = 2.7V to 3.6V; V _I = V _{CC} - 0.6V; I _O = 0			5	500	μA

NOTES:1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^\circ C$.

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AC CHARACTERISTICSGND = 0 V; $t_r = t_f \leq 2.5$ ns; $C_L = 50$ pF

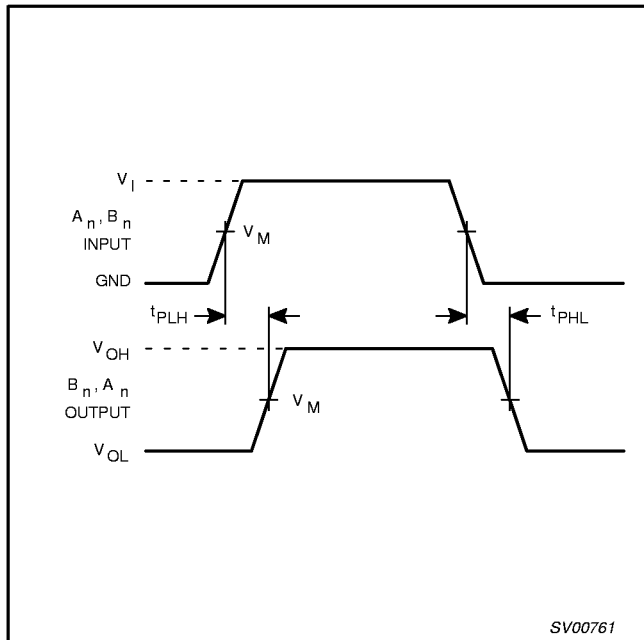
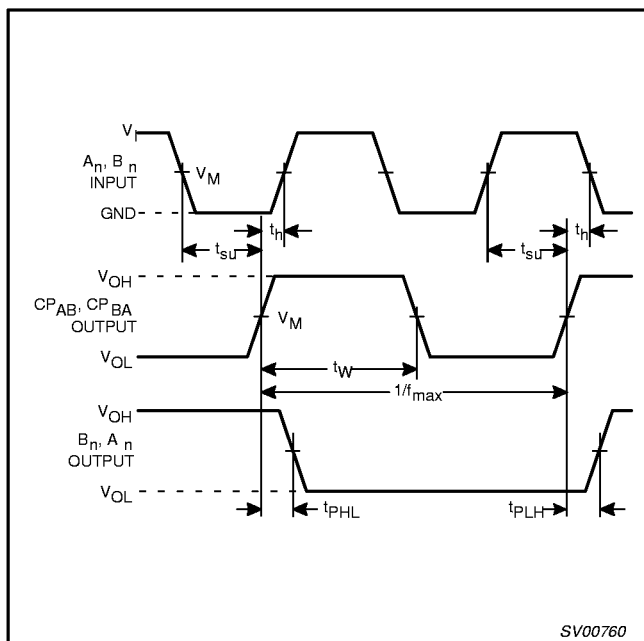
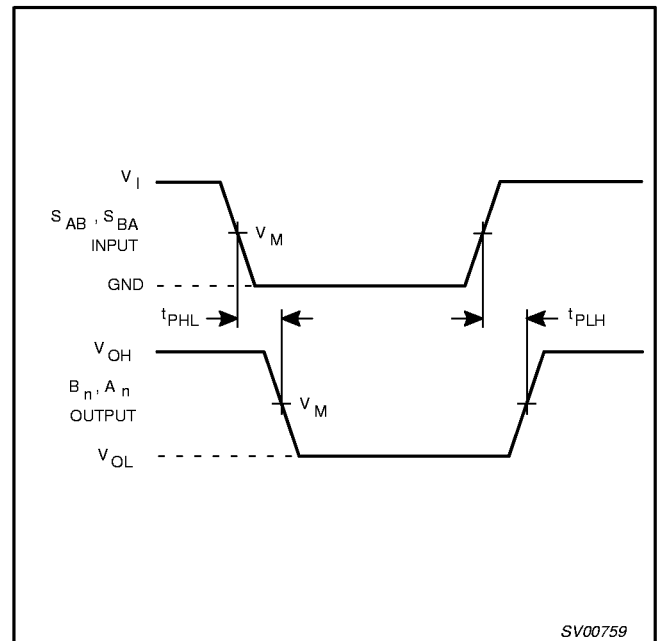
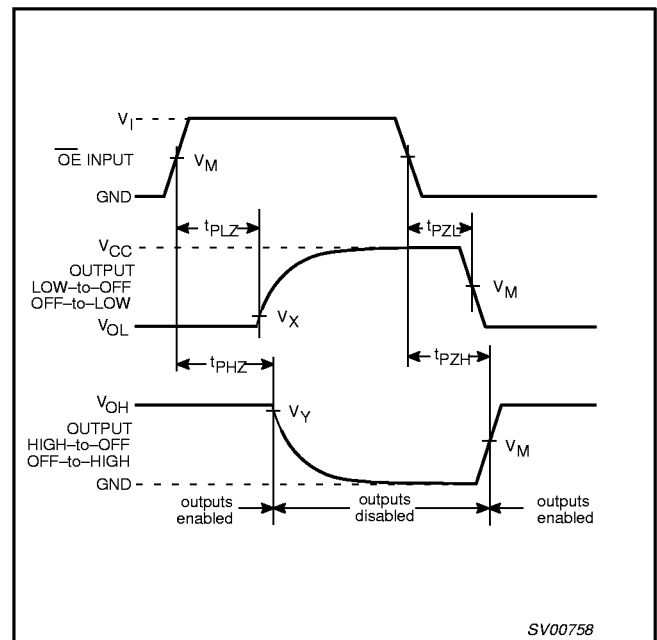
SYMBOL	PARAMETER	WAVEFORM	LIMITS						UNIT
			$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$		$V_{CC} = 1.2V$	
			MIN	TYP ¹	MAX	MIN	MAX	TYP	
t_{PHL}/t_{PLH}	Propagation delay An, Bn to Bn, An	Figures 1, 6	1.5	3.9	6.8	1.5	7.8	15	ns
t_{PHL}/t_{PLH}	Propagation delay CP _{AB} , CP _{BA} to B _n , A _n	Figures 2, 6	1.5	4.6	7.6	1.5	8.6	19	ns
t_{PHL}/t_{PLH}	Propagation delay S _{AB} , S _{BA} to B _n , A _n	Figures 3, 6	1.5	4.9	8.5	1.5	9.5	19	ns
t_{PZH}/t_{PZL}	3-State output enable time OEn to An, Bn	Figures 4, 6	1.5	4.5	7.8	1.5	8.8	20	ns
t_{PHZ}/t_{PLZ}	3-State output disable time OEn to An, Bn	Figures 4, 6	1.5	3.9	6.1	1.5	7.1	10	ns
t_{PZH}/t_{PZL}	3-State output enable time DIR to An, Bn	Figures 5, 6	1.5	4.6	7.9	1.5	8.9	20	ns
t_{PHZ}/t_{PLZ}	3-State output disable time DIR to An, Bn	Figures 5, 6	1.5	3.5	6.0	1.5	7.0	12	ns
t_W	Clock pulse width HIGH or LOW CP _{AB} or CP _{BA}	Figure 1, 3	3.3	1.9	—	3.3	—	—	ns
t_{su}	Set-up time An, Bn to CP _{AB} , CP _{BA}	Figure 2	1.6	0.35	—	1.6	—	—	ns
t_h	Hold time An, Bn to CP _{AB} , CP _{BA}	Figure 2	1.0	−0.3	—	1.0	—	—	ns
f_{max}	Maximum clock pulse frequency	Figure 2	150	250	—	125	—	—	ns

NOTE:1. These typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^\circ C$.

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AC WAVEFORMS

 $V_M = 1.5V$ at $V_{CC} \geq 2.7V$ $V_M = 0.5V \cdot V_{CC}$ at $V_{CC} < 2.7V$ V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load. $V_X = V_{OL} + 0.3V$ at $V_{CC} \geq 2.7V$ $V_X = V_{OL} + 0.1V_{CC}$ at $V_{CC} < 2.7V$ $V_Y = V_{OH} - 0.3V$ at $V_{CC} \geq 2.7V$ $V_Y = V_{OH} - 0.1V_{CC}$ at $V_{CC} < 2.7V$ Figure 1. Input A_n , B_n to output B_n , A_n propagation delays.Figure 2. A_n , B_n to CP_{AB} , CP_{BA} set-up and hold times, clock CP_{AB} , CP_{BA} pulse width, maximum clock pulse frequency and the CP_{AB} , CP_{BA} to output B_n , A_n propagation delays.Figure 3. Input S_{AB} , S_{BA} to output B_n , A_n propagation delay times.Figure 4. Input $\overline{OE}$ to output A_n , B_n 3-State enable and disable times.

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AC WAVEFORMS (Continued)

$V_M = 1.5V$ at $V_{CC} \geq 2.7V$
 $V_M = 0.5V * V_{CC}$ at $V_{CC} < 2.7V$
 V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.
 $V_X = V_{OL} + 0.3V$ at $V_{CC} \geq 2.7V$
 $V_X = V_{OL} + 0.1V_{CC}$ at $V_{CC} < 2.7V$
 $V_Y = V_{OH} - 0.3V$ at $V_{CC} \geq 2.7V$
 $V_Y = V_{OH} - 0.1V_{CC}$ at $V_{CC} < 2.7V$

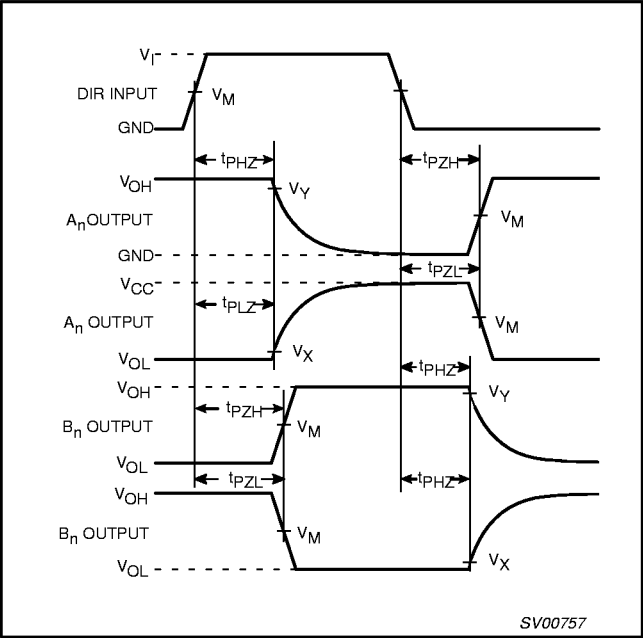


Figure 5. Input DIR to output A_n, B_n 3-State enable and disable times.

TEST CIRCUIT

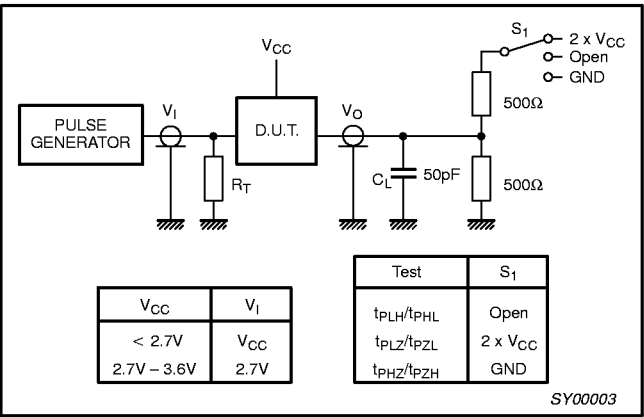


Figure 6. Load circuitry for switching times.

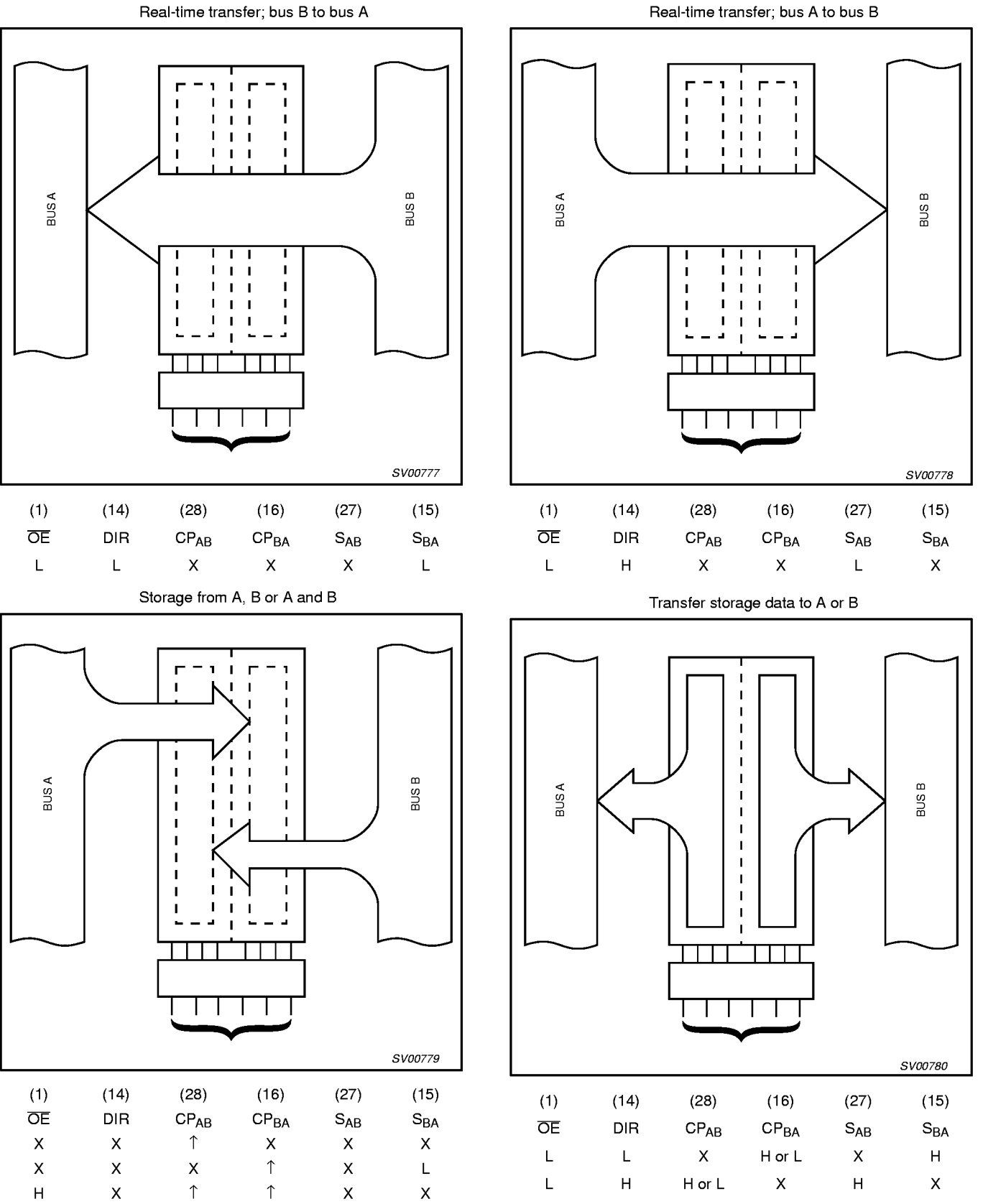
V_{CC}	V_I
$< 2.7V$	V_{CC}
$2.7V - 3.6V$	$2.7V$

Test	S_1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	$2 \times V_{CC}$
t_{PHZ}/t_{PZH}	GND

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APPLICATION INFORMATION

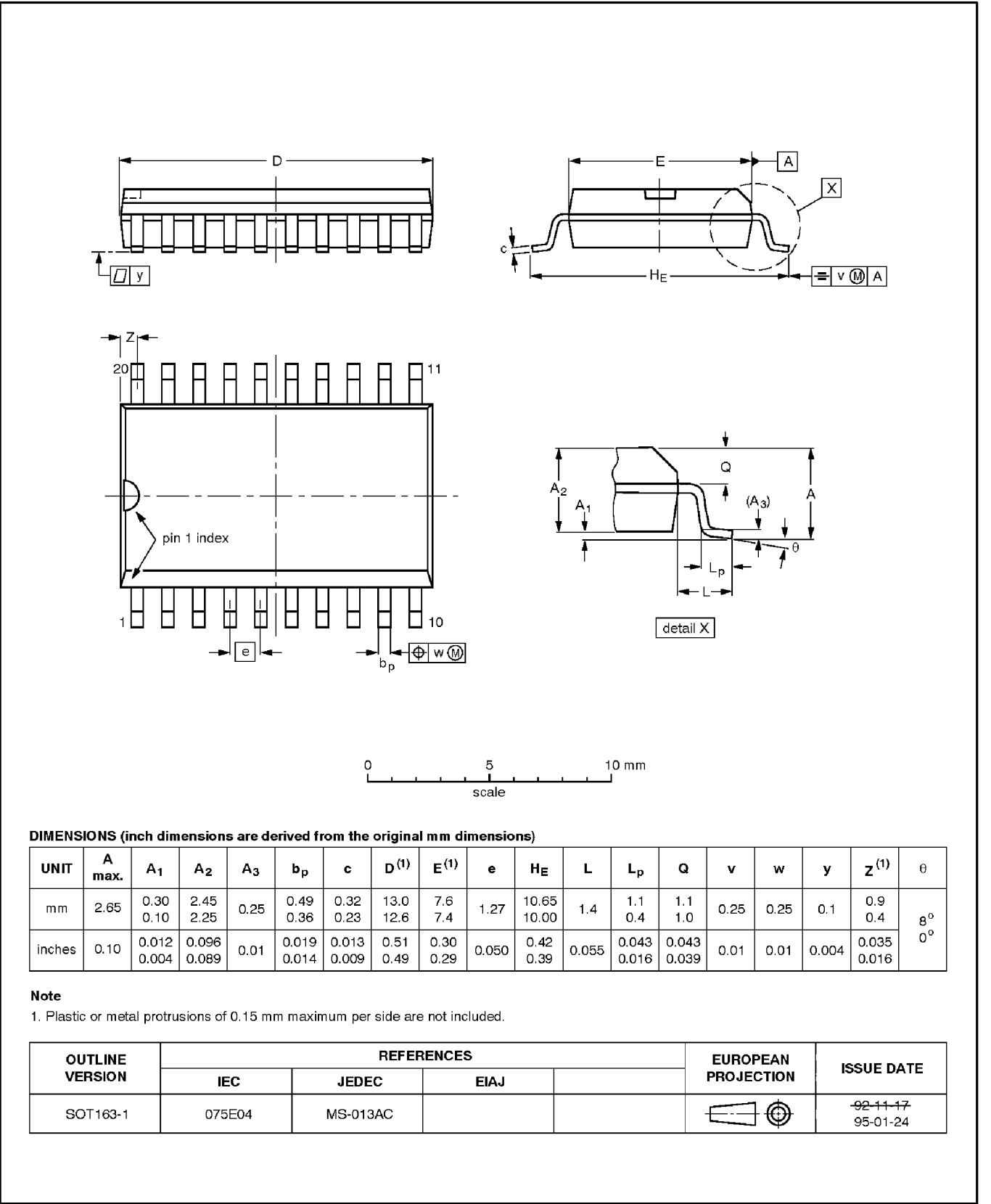


Octal bus transceiver/register (3-State)

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SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1

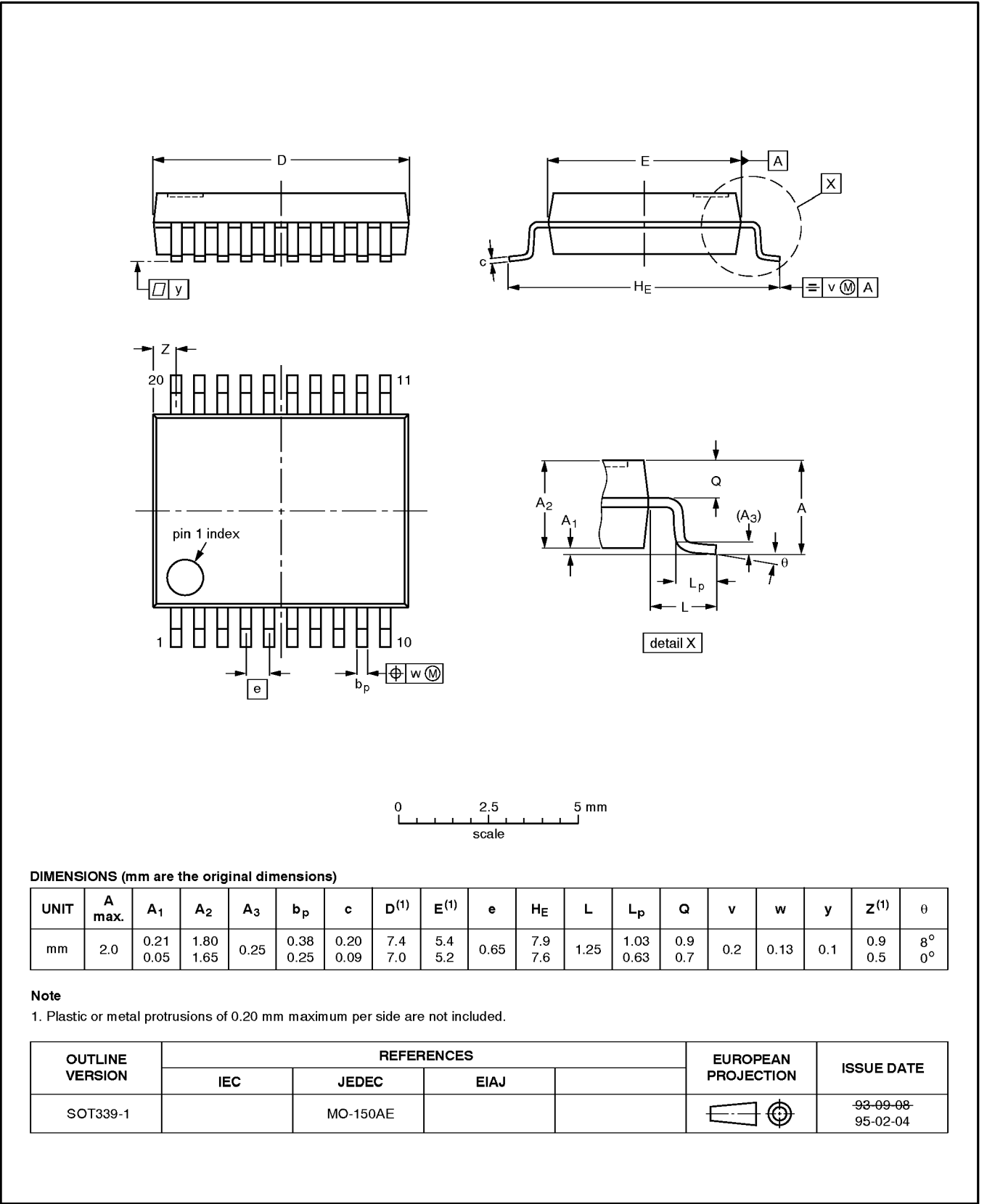


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SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



Octal bus transceiver/register (3-State)

74LVC646A

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1

